

74LVT244B; 74LVTH244B

3.3 V octal buffer/line driver; 3-state

Rev. 03 — 3 March 2006

Product data sheet

1. General description

The 74LVT244B; 74LVTH244B is a high-performance BiCMOS product designed for V_{CC} operation at 3.3 V.

This device is an octal buffer that is ideal for driving bus lines. The device features two output enable inputs ($\overline{1OE}$ and $\overline{2OE}$), each controlling four of the 3-state outputs.

2. Features

- Octal bus interface
- 3-state buffers
- Speed upgrade of 74LVT244A
- Output capability: +64 mA and -32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus hold data inputs eliminate need for external pull-up resistors to hold unused inputs
- Power-up 3-state
- Live insertion and extraction permitted
- No bus current loading when output is tied to 5 V bus
- Latch-up protection:
 - ◆ JESD78: exceeds 500 mA
- ESD protection:
 - ◆ HBM EIA/JESD22-A114-C exceeds 2000 V
 - ◆ MM EIA/JESD22-A115-A 200 V

3. Quick reference data

Table 1. Quick reference data

$GND = 0 V$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|--|--|-----|-----|-----|------|
| t_{PLH} | LOW-to-HIGH propagation delay nAn to nYn | $C_L = 50\text{ pF}$; $V_{CC} = 3.3\text{ V}$ | - | 1.9 | - | ns |
| t_{PHL} | HIGH-to-LOW propagation delay nAn to nYn | $C_L = 50\text{ pF}$; $V_{CC} = 3.3\text{ V}$ | - | 2.0 | - | ns |

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Table 1. Quick reference data ...continued

 $GND = 0\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

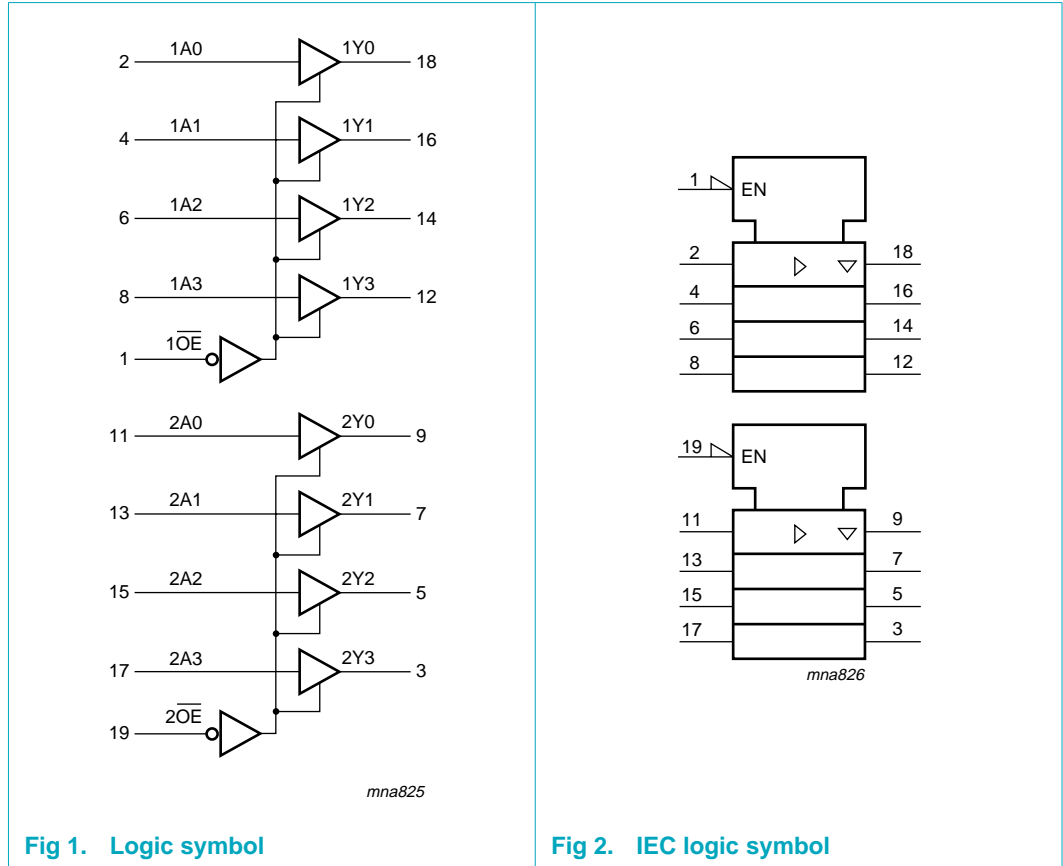
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------|--------------------------|--|-----|------|-----|------|
| C_i | input capacitance | $V_I = 0\text{ V}$ or 3.0 V | - | 4 | - | pF |
| C_o | output capacitance | outputs disabled; $V_O = 0\text{ V}$ or 3.0 V | - | 8 | - | pF |
| I_{CC} | quiescent supply current | outputs disabled; $V_{CC} = 3.6\text{ V}$; $I_O = 0\text{ A}$; $V_I = GND$ or V_{CC} | - | 0.13 | - | mA |

4. Ordering information

Table 2. Ordering information

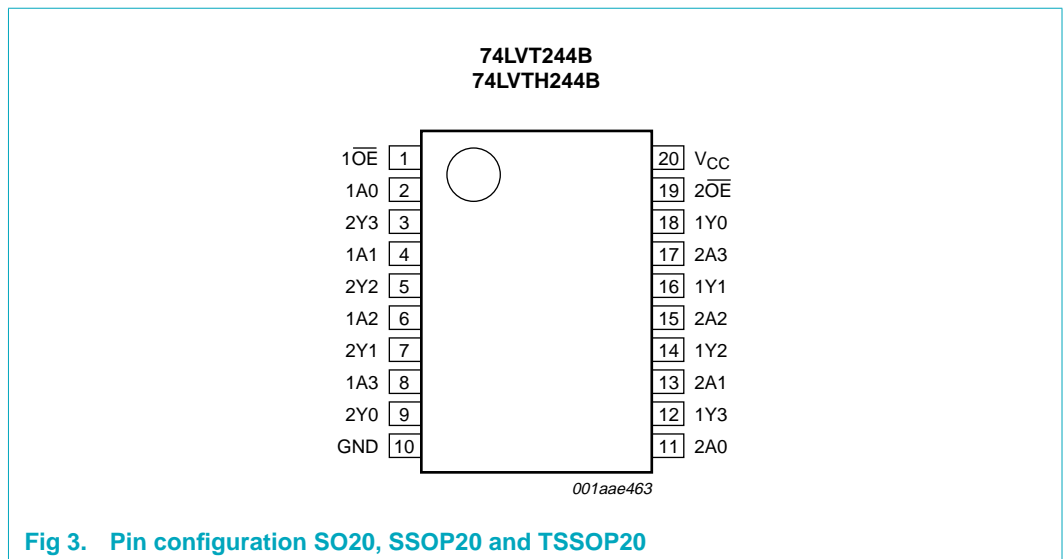
| Type number | Package | | | |
|--------------|-------------------|---------|---|----------|
| | Temperature range | Name | Description | Version |
| 74LVT244BD | -40 °C to +85 °C | SO20 | plastic small outline package; 20 leads; body width 7.5 mm | SOT163-1 |
| 74LVT244BDB | -40 °C to +85 °C | SSOP20 | plastic shrink small outline package; 20 leads; body width 5.3 mm | SOT339-1 |
| 74LVT244BPW | -40 °C to +85 °C | TSSOP20 | plastic thin shrink small outline package; 20 leads; body width 4.4 mm | SOT360-1 |
| 74LVTH244BD | -40 °C to +85 °C | SO20 | plastic small outline package; 20 leads; body width 7.5 mm | SOT163-1 |
| 74LVTH244BDB | -40 °C to +85 °C | SSOP20 | plastic shrink small outline package; 20 leads; body width 5.3 mm | SOT339-1 |
| 74LVTH244BPW | -40 °C to +85 °C | TSSOP20 | plastic thin shrink small outline package; 20 leads; body width 4.4 mm | SOT360-1 |

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|------------------|-----|-----------------------|
| $1\overline{OE}$ | 1 | 1 output enable input |
| 1A0 | 2 | 1 data input 0 |
| 2Y3 | 3 | 2 data output 3 |
| 1A1 | 4 | 1 data input 1 |
| 2Y2 | 5 | 2 data output 2 |
| 1A2 | 6 | 1 data input 2 |
| 2Y1 | 7 | 2 data output 1 |
| 1A3 | 8 | 1 data input 3 |
| 2Y0 | 9 | 2 data output 0 |
| GND | 10 | ground (0 V) |
| 2A0 | 11 | 2 data input 0 |
| 1Y3 | 12 | 1 data output 3 |
| 2A1 | 13 | 2 data input 1 |
| 1Y2 | 14 | 1 data output 2 |
| 2A2 | 15 | 2 data input 2 |
| 1Y1 | 16 | 1 data output 1 |
| 2A3 | 17 | 2 data input 3 |
| 1Y0 | 18 | 1 data output 0 |
| $2\overline{OE}$ | 19 | 2 output enable input |
| V _{CC} | 20 | supply voltage |

7. Functional description

7.1 Function table

Table 4. Function table ^[1]

| Control | Input | Output |
|------------------|-------|--------|
| $n\overline{OE}$ | nAn | nYn |
| L | L | L |
| | H | H |
| H | X | Z |

- [1] H = HIGH voltage level;
 L = LOW voltage level;
 X = don't care;
 Z = high-impedance OFF-state.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|-----------------------------------|----------|------|------|
| V_{CC} | supply voltage | | -0.5 | +4.6 | V |
| V_I | input voltage | | [1] -0.5 | +7.0 | V |
| V_O | output voltage | output in OFF-state or HIGH-state | [1] -0.5 | +7.0 | V |
| I_{IK} | input clamping current | $V_I < 0$ V | - | -50 | mA |
| I_{OK} | output clamping current | $V_O < 0$ V | - | -50 | mA |
| I_O | output current | output in LOW-state | - | 128 | mA |
| | | output in HIGH-state | - | -64 | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| T_j | junction temperature | | [2] - | 150 | °C |

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------------|-------------------------------------|---|-----|-----|-----|------|
| V_{CC} | supply voltage | | 2.7 | - | 3.6 | V |
| V_I | input voltage | | 0 | - | 5.5 | V |
| V_{IH} | HIGH-state input voltage | | 2.0 | - | - | V |
| V_{IL} | LOW-state input voltage | | - | - | 0.8 | V |
| I_{OH} | HIGH-state output current | | - | - | -32 | mA |
| I_{OL} | LOW-state output current | none | - | - | 32 | mA |
| | | current duty cycle ≤ 50 %; $f_i \geq 1$ kHz | - | - | 64 | mA |
| T_{amb} | ambient temperature | in free-air | -40 | - | +85 | °C |
| $\Delta t/\Delta V$ | input transition rise and fall rate | outputs enabled | - | - | 10 | ns/V |

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|--|------------------------------------|--|---|----------------|-----------|---------------|---------------|
| $T_{amb} = -40\text{ °C to }+85\text{ °C}$ [1] | | | | | | | |
| V_{IK} | input clamping voltage | $V_{CC} = 2.7\text{ V}; I_{IK} = -18\text{ mA}$ | - | -0.9 | -1.2 | V | |
| V_{OH} | HIGH-state output voltage | $V_{CC} = 2.7\text{ V}$ | | | | | |
| | | $I_{OH} = -100\text{ }\mu\text{A}$ | $V_{CC} - 2.0$ | $V_{CC} - 2.1$ | - | V | |
| | | $I_{OH} = -8\text{ mA}$ | 2.4 | 2.5 | - | V | |
| | | $V_{CC} = 3.0\text{ V}$ | | | | | |
| V_{OL} | LOW-state output voltage | $V_{CC} = 2.7\text{ V}$ | | | | | |
| | | $I_{OL} = 100\text{ }\mu\text{A}$ | - | 0.1 | 0.2 | V | |
| | | $I_{OL} = 24\text{ mA}$ | - | 0.3 | 0.5 | V | |
| | | $V_{CC} = 3.0\text{ V}$ | | | | | |
| V_{OL} | LOW-state output voltage | $V_{CC} = 3.0\text{ V}$ | | | | | |
| | | $I_{OL} = 16\text{ mA}$ | - | 0.25 | 0.4 | V | |
| | | $I_{OL} = 32\text{ mA}$ | - | 0.3 | 0.5 | V | |
| | | $I_{OL} = 64\text{ mA}$ | - | 0.4 | 0.55 | V | |
| I_{LI} | input leakage current | all pins | $V_{CC} = 0\text{ V or }3.6\text{ V}; V_I = 5.5\text{ V}$ | - | 0.1 | 10 | μA |
| | | control pins | $V_{CC} = 3.6\text{ V}; V_I = V_{CC}\text{ or GND}$ | - | ± 0.1 | ± 1 | μA |
| | | I/O data pins | $V_{CC} = 3.6\text{ V}$ | [2] | | | |
| | | | $V_I = V_{CC}$ | - | 0.1 | 1 | μA |
| | | $V_I = 0\text{ V}$ | - | -1 | -5 | μA | |
| I_{OFF} | power-off leakage current | $V_{CC} = 0\text{ V}; V_I\text{ or }V_O = 0\text{ V to }4.5\text{ V}$ | - | 1 | ± 100 | μA | |
| I_{HOLD} | bus hold current data input | $V_{CC} = 3\text{ V}$ | [3] | | | | |
| | | $V_I = 0.8\text{ V}$ | 75 | 130 | - | μA | |
| | | $V_I = 2.0\text{ V}$ | -75 | -140 | - | μA | |
| | | $V_{CC} = 0\text{ V to }3.6\text{ V}$ | | | | | |
| | | $V_I = 3.6\text{ V}$ | ± 500 | - | - | μA | |
| I_{EX} | external current into output | output in HIGH-state when $V_O > V_{CC}; V_O = 5.5\text{ V}; V_{CC} = 3.3\text{ V}$ | - | 60 | 125 | μA | |
| $I_{O(pu/pd)}$ | power-up/power-down output current | $V_{CC} \leq 1.2\text{ V}; V_O = 0.5\text{ V to }V_{CC}; V_I = \text{GND or }V_{CC}; \overline{nOE} = \text{don't care}$ | [4] | ± 1 | ± 100 | μA | |
| I_{OZ} | OFF-state output current | $V_{CC} = 3.6\text{ V}; V_I = V_{IH}\text{ or }V_{IL}$ | | | | | |
| | | output HIGH: $V_O = 3.0\text{ V}$ | - | 1 | 5 | μA | |
| | | output LOW: $V_O = 0.5\text{ V}$ | - | -1 | -5 | μA | |
| I_{CC} | quiescent supply current | $V_{CC} = 3.6\text{ V}; V_I = \text{GND or }V_{CC}; I_O = 0\text{ A}$ | | | | | |
| | | output HIGH | - | 0.13 | 0.19 | mA | |
| | | output LOW | - | 2 | 5 | mA | |
| | | outputs disabled | [5] | - | 0.13 | 0.19 | mA |

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------|-------------------------------------|---|-------|-----|-----|------|
| ΔI_{CC} | additional quiescent supply current | per input pin; $V_{CC} = 3.0\text{ V to }3.6\text{ V}$; one input at $V_{CC} - 0.6\text{ V}$ and other inputs at V_{CC} or GND | [6] - | 0.1 | 0.2 | mA |
| C_i | input capacitance | $V_i = 0\text{ V or }3.0\text{ V}$ | - | 4 | - | pF |
| C_o | output capacitance | outputs disabled; $V_o = 0\text{ V or }3.0\text{ V}$ | - | 8 | - | pF |

[1] Typical values are measured at $T_{amb} = 25\text{ }^\circ\text{C}$.[2] Unused pins at V_{CC} or GND.

[3] This is the bus hold overdrive current required to force the input to the opposite logic state.

[4] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. From $V_{CC} = 1.2\text{ V}$ to $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ a transition time of 100 μs is permitted. This parameter is valid for $T_{amb} = 25\text{ }^\circ\text{C}$ only.[5] I_{CC} is measured with outputs pulled to V_{CC} or GND.[6] This is the increase in supply current for each input at $V_{CC} - 0.6\text{ V}$.

11. Dynamic characteristics

Table 8. Dynamic characteristicsVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 6](#).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|--|---|-----|-----|-----|------|
| $T_{amb} = -40\text{ }^\circ\text{C to }+85\text{ }^\circ\text{C}$ [1] | | | | | | |
| t_{PLH} | LOW-to-HIGH propagation delay nAn to nYn | see Figure 4 | | | | |
| | | $V_{CC} = 2.7\text{ V}$ | - | - | 3.8 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | 1.1 | 1.9 | 3.5 | ns |
| t_{PHL} | HIGH-to-LOW propagation delay nAn to nYn | see Figure 4 | | | | |
| | | $V_{CC} = 2.7\text{ V}$ | - | - | 3.6 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | 1.3 | 2.0 | 3.3 | ns |
| t_{PZH} | output enable time to HIGH-level \overline{nOE} to nYn | see Figure 5 | | | | |
| | | $V_{CC} = 2.7\text{ V}$ | - | - | 5.3 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | 1.1 | 2.8 | 4.5 | ns |
| t_{PZL} | output enable time to LOW-level \overline{nOE} to nYn | see Figure 5 | | | | |
| | | $V_{CC} = 2.7\text{ V}$ | - | - | 4.9 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | 1.4 | 2.3 | 4.4 | ns |
| t_{PHZ} | output disable time from HIGH-level \overline{nOE} to nYn | see Figure 5 | | | | |
| | | $V_{CC} = 2.7\text{ V}$ | - | - | 4.5 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | 1.9 | 2.9 | 4.4 | ns |
| t_{PLZ} | output disable time from LOW-level \overline{nOE} to nYn | see Figure 5 | | | | |
| | | $V_{CC} = 2.7\text{ V}$ | - | - | 4.4 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | 1.8 | 2.5 | 4.4 | ns |

[1] Typical values are measured at $V_{CC} = 3.3\text{ V}$ and $T_{amb} = 25\text{ }^\circ\text{C}$.

12. Waveforms

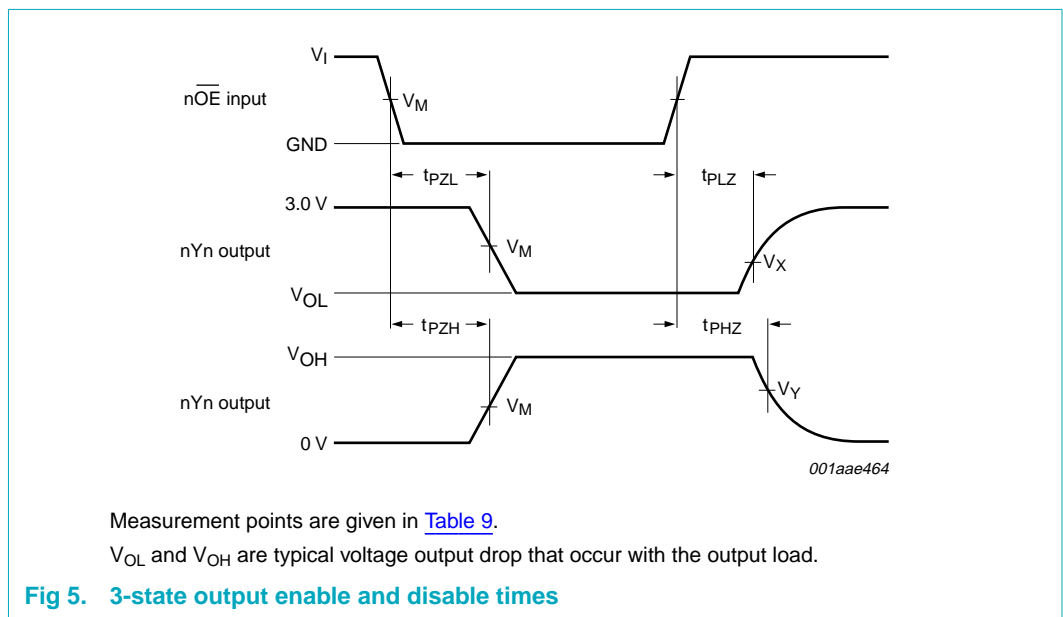
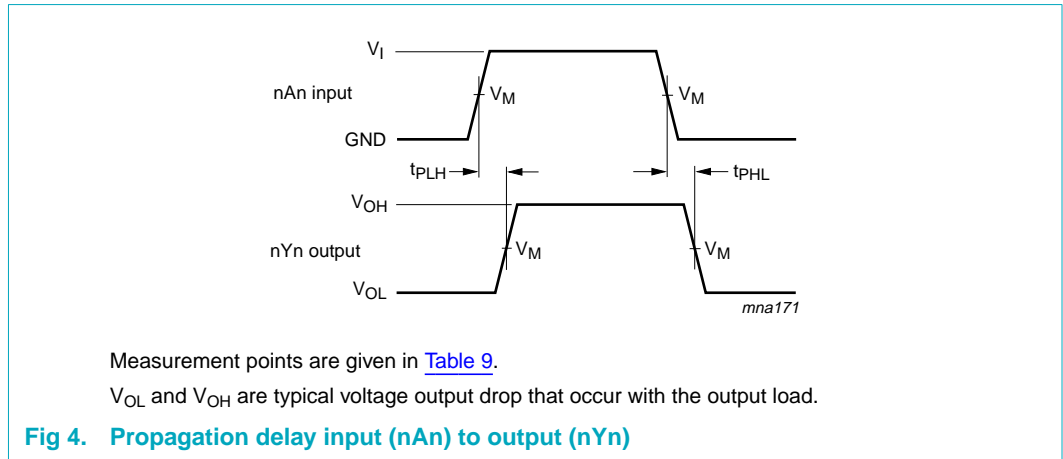


Table 9. Measurement points

| Input | Output | | |
|-------|--------|------------------|------------------|
| V_M | V_M | V_X | V_Y |
| 1.5 V | 1.5 V | $V_{OL} + 0.3 V$ | $V_{OH} - 0.3 V$ |

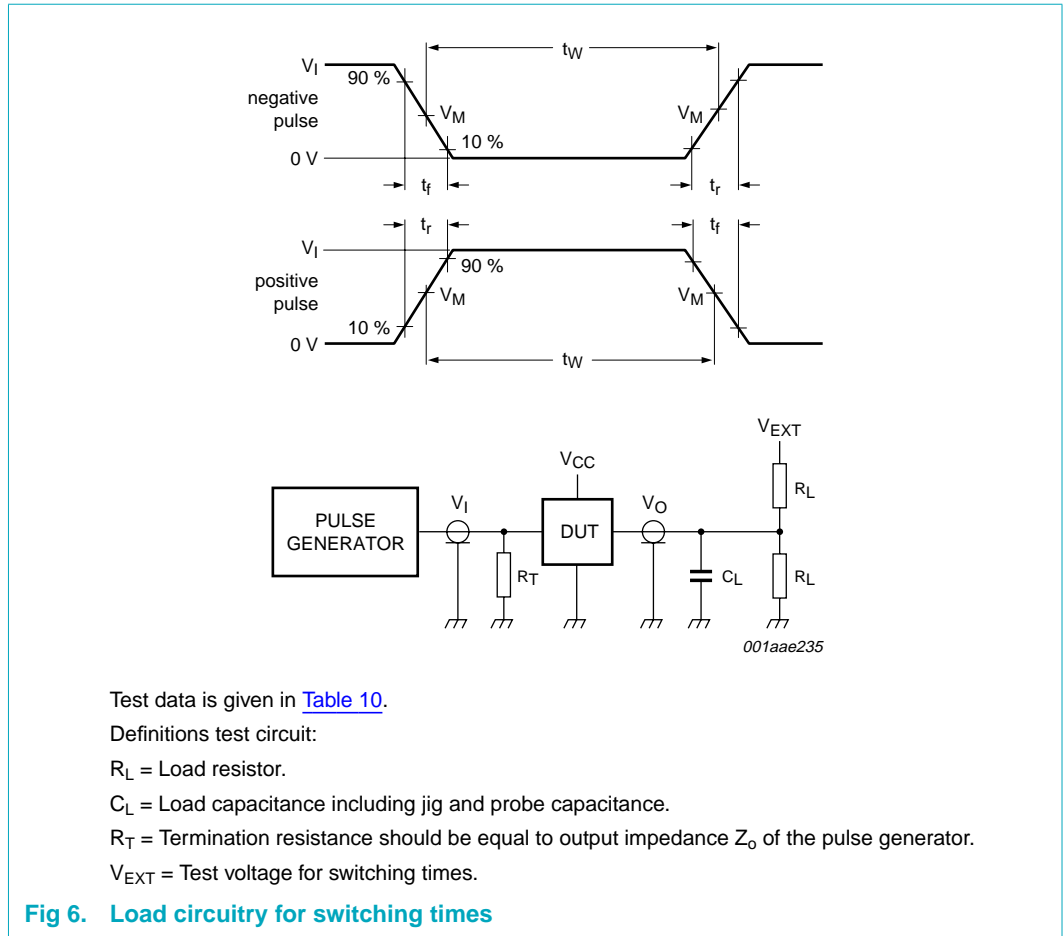


Table 10. Test data

| Input | | | | Load | | V_{EXT} | | |
|-------|---------------|--------|---------------|-------|--------------|--------------------|--------------------|--------------------|
| V_I | f_i | t_w | t_r, t_f | C_L | R_L | t_{PHZ}, t_{PZH} | t_{PLZ}, t_{PZL} | t_{PLH}, t_{PHL} |
| 2.7 V | ≤ 10 MHz | 500 ns | ≤ 2.5 ns | 50 pF | 500 Ω | GND | 6 V | open |

13. Package outline

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

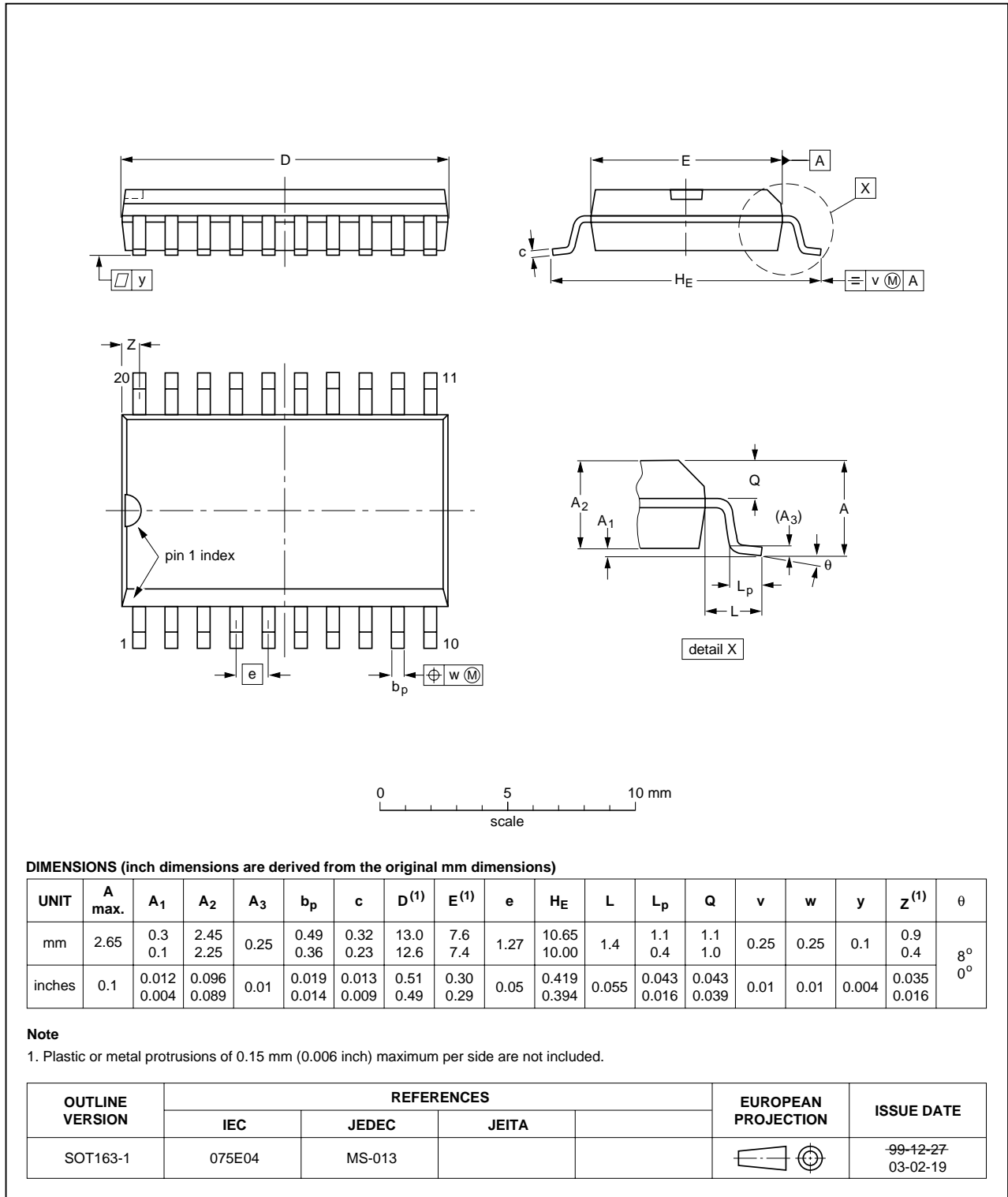


Fig 7. Package outline SOT163-1 (SO20)

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1

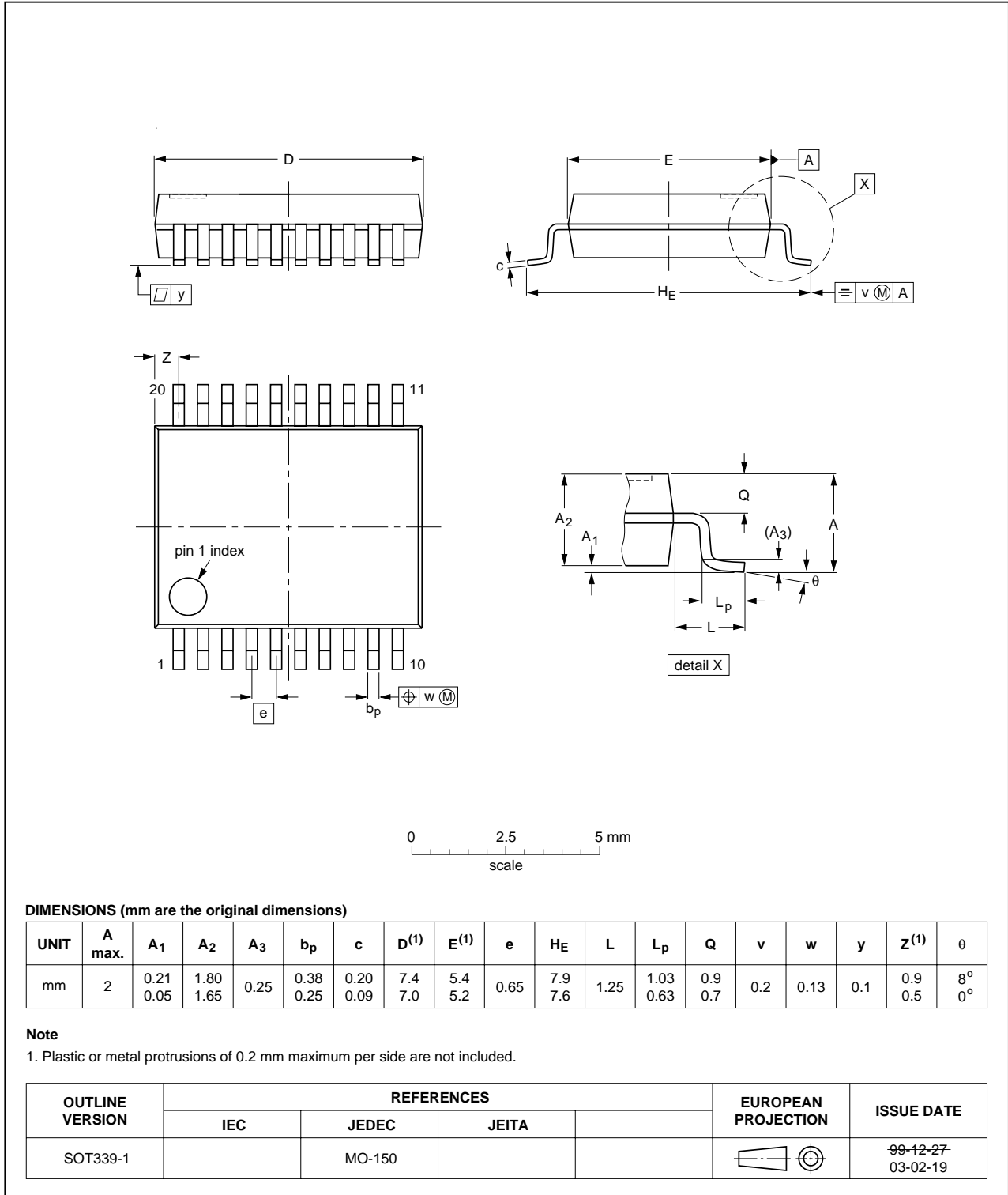


Fig 8. Package outline SOT339-1 (SSOP20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

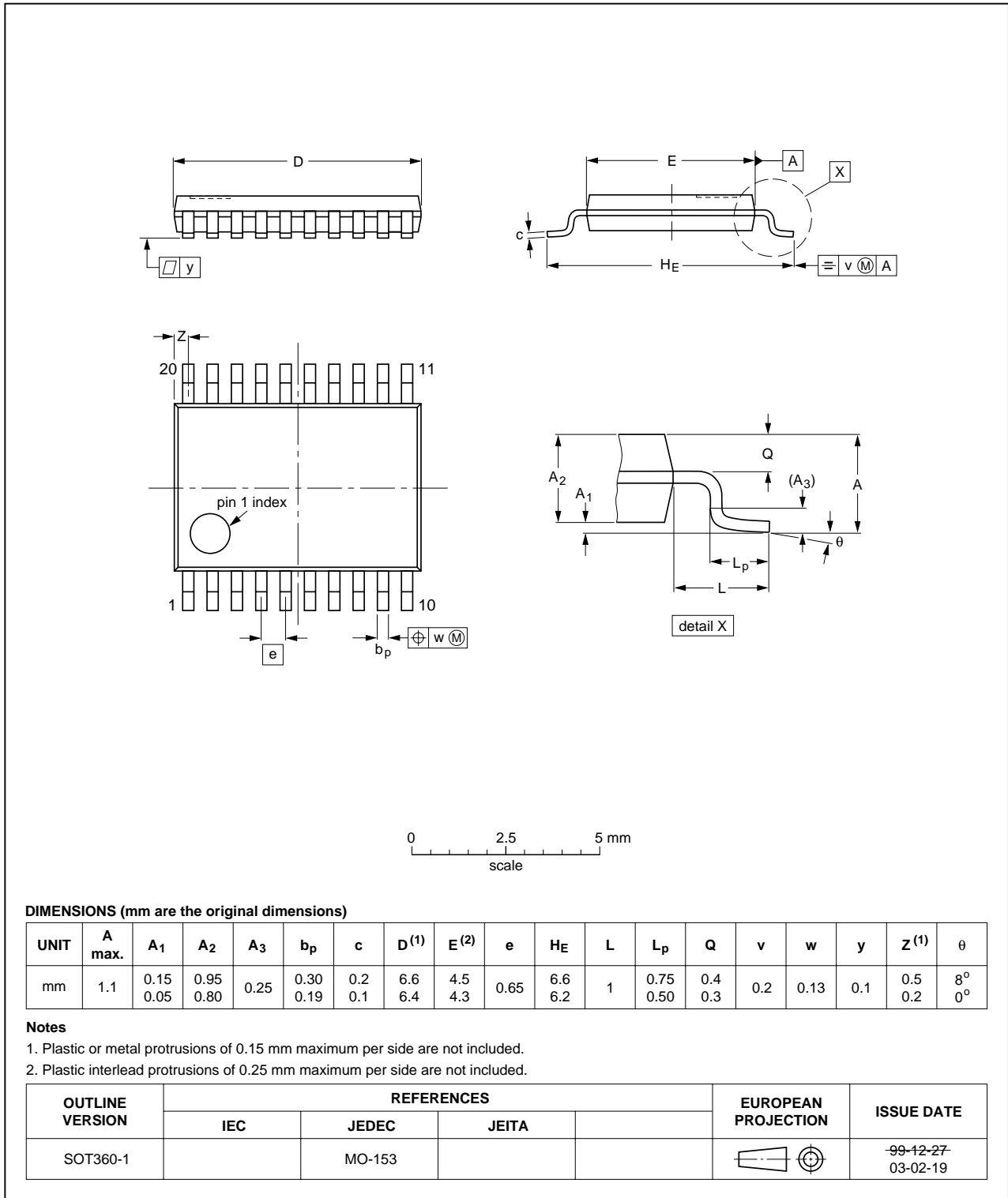


Fig 9. Package outline SOT360-1 (TSSOP20)

14. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|---|
| BiCMOS | Bipolar Complementary Metal Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

15. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|------------------|--|-----------------------|---------------|------------------------------|
| 74LVT_LVTH244B_3 | 20060303 | Product data sheet | - | 74LVT244B_2 (9397 750 11918) |
| Modifications: | <ul style="list-style-type: none"> The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors. Section 4: Added type numbers 74LVTH244BD, 74LVTH244BDB and 74LVTH244BPW. | | | |
| 74LVT244B_2 | 20030919 | Product specification | - | 74LVT244B_1 (9397 750 04814) |
| 74LVT244B_1 | 19981101 | Product specification | - | - |

16. Legal information

16.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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